Technical Data Sheet



SPDT Ramses 1.85mm 67GHz Failsafe 12Vdc TTL Diodes Pins Terminals

PAGE 1/2 ISSUE 12-09-22 SERIE: SPDT PART NUMBER: R570V12100

RF CHARACTERISTICS

Frequency range : 0 - 67 GHz Impedance : 50 Ohms

Frequency (GHz)	DC - 6	6 - 12.4	12.4 - 18	18 - 26.5	26.5 - 40	40 - 50	50 - 67
VSWR max	1.30	1.40	1.50	1.70	1.90	1.90	1.90
Insertion loss max	0.30 dB	0.40 dB	0.50 dB	0.70 dB	0.80 dB	1.10 dB	1.10 dB
Isolation min	70 dB	60 dB	60 dB	55 dB	50 dB	50 dB	50 dB
Average power (*)	80 W	60 W	50 W	20 W	10 W	5 W	3 W

ELECTRICAL CHARACTERISTICS

Actuator : FAILSAFE
Nominal current ** : 250 mA

Actuator voltage (Vcc) : 12V (10.2 to 13V)

Terminals : solder pins (250°C max. / 30 sec.) TTL inputs (E) - High level : 2.2 to 5.5 V / $800\mu A$ at 5.5 V

- Low level : 0 to 0.8 V / 20µA at 0.8 V

MECHANICAL CHARACTERISTICS

Connectors : 1.85mm female (Accoding to IEEE STD 287)

Life : 2 million cycles

Switching Time*** : < 10 msConstruction : Splashproof
Weight : < 45 g

ENVIRONMENTAL CHARACTERISTICS

Operating temperature range : -25°C to +70°C
Storage temperature range : -40°C to +85°C

(* Average power at 25°C per RF Path)

(** At 25° C ±10%)

(*** Nominal voltage; 25° C)



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